



8

7

6

5

SS

EN

FB

COMP

(Top View)

FP

SO-8EP

18V. 3A SYNCHRONOUS DC-DC BUCK CONVERTER

Pin Assignments

BS

IN

SW

GND

Applications

Monitor

Datacom

TV

STB

1

2

3

4

Description

The AP3513E is a 500kHz fixed frequency, current mode, PWM synchronous buck (step-down) DC-DC converter, capable of driving a 3A load with high efficiency, excellent line and load regulation. The AP3513E exhibits high efficiency at light load. The device integrates N-channel power MOSFET switch with low on-resistance. Current mode control provides fast transient response and cycle-by-cycle current limit.

The AP3513E employs complete protection to ensure system security, including output Over Voltage Protection, input Under Voltage Lock Out, programmable Soft-start, Over Temperature Protection and hiccup mode Short Circuit Protection.

This IC is available in SO-8EP package.

Features

- Input Voltage Range: 4.5V to 18V •
- Fixed 500kHz Frequency
- High Efficiency at Light Load
- Output Current: 3A
- **Current Mode Control**
- **Built-In Over Current Protection**
- **Built-In Thermal Shutdown Function**
- **Built-In UVLO Function**
- **Built-In Over Voltage Protection**
- Programmable Soft-Start
- Hiccup Mode SCP
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free, "Green" Device (Note 3)
- For automotive applications requiring specific change. control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Typical Applications Circuit





Pin Descriptions

Pin Number	Pin Name	Function
1	BS	Bootstrap pin. A bootstrap capacitor is connected between the BS pin and SW pin. The voltage across the bootstrap capacitor drives the internal high-side NMOS switch.
2	IN	Supply input pin. A capacitor should be connected between the IN pin and GND pin to keep the DC input voltage constant.
3	SW	Power switch output pin. This pin is connected to the inductor and bootstrap capacitor.
4	GND	Ground pin
5	FB	Feedback pin. This pin is connected to an external resistor divider to program the system output voltage. When the FB pin voltage exceeds 1.1V, the over voltage protection is triggered. When the FB pin voltage is below 0.3V, the oscillator frequency is lowered to realize short circuit protection.
6	COMP	Compensation pin. This pin is the output of the transconductance error amplifier and the input to the current comparator. This pin is used to compensate the control loop. Connect a series RC network from this pin to GND pin. In some cases, an additional capacitor from this pin to GND pin is required.
7	EN	Enable Input. EN is a digital input that turns the regulator on or off. Drive EN high to turn on the regulator, drive it low to turn off. Pull up with $100k\Omega$ resistor for automatic startup.
8	SS	Soft-start control input pin. SS controls the soft start period. Connect a capacitor from SS to GND to set the soft-start period. A 0.1µF capacitor sets the soft-start period to 15ms. To disable the soft-start feature, leave SS unconnected.
_	EP	Exposed pad. It should be connected to GND in PCB layout.

Functional Block Diagram





Absolute Maximum Ratings (Note 4)

Symbol	Parameter	Rating	Unit
V _{IN}	IN Pin Voltage	-0.3 to 20	V
V _{EN}	EN Pin Voltage	-0.3 to V _{IN}	V
Vsw	SW Pin Voltage	21	V
V _{BS}	BS Pin Voltage	-0.3 to V _{SW} +6	V
V _{FB}	FB Pin Voltage	-0.3 to 6	V
V _{COMP}	COMP Pin Voltage	-0.3 to 6	V
V _{SS}	SS Pin Voltage	-0.3 to 6	V
TJ	Operating Junction Temperature	+150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
T _{LEAD}	Lead Temperature (Soldering, 10s)	+260	°C
θ_{JA}	Thermal Resistance (Junction to Ambient)	SO-8EP 60	°C/W
V _{HBM}	ESD (Human Body Model)	2000	V
V _{MM}	ESD (Machine Model)	200	V

Note 4: Stresses greater than those listed under "Absolute Maximum Ratings" can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods can affect device reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Мах	Unit
ViN	Input Voltage	4.5	18	V
T _A	Operating Ambient Temperature	-40	+85	°C



Electrical Characteristics ($V_{IN} = V_{EN} = 12V$, $V_{OUT} = 3.3V$, $T_A = +25^{\circ}C$, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
SUPPLY VOLT	AGE (IN PIN)					
V _{IN}	Input Voltage	_	4.5		18	V
lq	Quiescent Current	V _{FB} = 1V, V _{EN} = 3.3V	_	1.2	1.4	mA
I _{SHDN}	Shutdown Supply Current	V _{EN} = 0V		0.1	1.0	μA
UNDER VOLTA	GE LOCKOUT					
V _{UVLO}	Input UVLO Threshold	V _{IN} Rising	3.65	4.0	4.25	V
V _{HYS}	Input UVLO Hysteresis	-	_	0.2	—	V
ENABLE (EN P	IN)					
_	EN Shutdown Threshold Voltage	-	1.1	1.5	2	V
_	EN Shutdown Threshold Voltage Hysteresis (Note 5)	-		350	_	mV
_	EN Lockout Threshold Voltage	-	2.2	2.5	2.7	V
_	EN Lockout Hysteresis		_	210	_	mV
VOLTAGE REF	ERENCE (FB PIN)					
V _{FB}	Feedback Voltage		0.907	0.925	0.943	V
V _{FBOV}	Feedback Over Voltage Threshold	-	—	1.1	_	V
I _{FB}	Feedback Bias Current	V _{FB} = 1V	-0.1	—	0.1	μA
MOSFET			-	-		-
RDSONH	High-Side Switch On-Resistance (Note 6)	I _{SW} = 0.2A and 0.7A	—	100	—	mΩ
R _{DSONL}	Low-Side Switch On-Resistance (Note 6)	I _{SW} = -0.2A and -0.7A	—	100	_	mΩ
CURRENT LIM	I A A A A A A A A A A A A A A A A A A A	-	-	-		-
I _{LEAKH}	High-Side Switch Leakage Current	V_{IN} = 18V, V_{EN} = 0V, V_{SW} = 0V	_	0.1	10	μA
I _{LIMH}	High-Side Switch Current Limit	_	4.3	5.6	_	А
ILIML	Low-Side Switch Current Limit	From drain to source	_	50	_	mA
SWITCHING RE	EGULATOR					
f _{OSC1}	Oscillator Frequency	_	410	500	590	kHz
f _{OSC2}	Short Circuit Oscillator Frequency	_	_	180		kHz
D _{MAX}	Maximum Duty Cycle	V _{FB} = 0.85V	_	90		%
D _{MIN}	Minimum Duty Cycle	V _{FB} = 1V	_	_	0	%



Electrical Characteristics (continued, V_{IN} = V_{EN} = 12V, V_{OUT} = 3.3V, T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit		
ERROR AMPL	IFIER							
A _{EA}	Error Amplifier Voltage Gain (Note 5)	-	—	400	_	V/V		
GEA	Error Amplifier Transconductance	_	_	800	_	μA/V		
G _{CS}	COMP to Current Sense Transconductance	_	-/	5.2	_	A/V		
THERMAL SHU	JTDOWN		\mathbf{N}					
T _{OTSD}	Thermal Shutdown (Note 5)	-		+160	—	°C		
T _{HYS}	Thermal Shutdown Hysteresis (Note 5)	-	-	+30		°C		
SOFT START ((SS PIN)							
tss	Soft-Start Time (Note 5)	C _{SS} = 0.1µF	<u> </u>	15	_	ms		
_	Soft-Start Current	-		5	_	μA		
$- Soft-Start Current - 5 - \mu A$ otes: 5. Not tested, guaranteed by design. 6. R _{DS(ON)} = $\frac{V_{SW1} - V_{SW2}}{I_{SW1} - I_{SW2}}$								



Performance Characteristics (V_{IN} = 12V, V_{OUT} = 3.3V, L = 4.7µH, T_A = +25°C, unless otherwise noted.)



Time (100µs/div)

Time (100µs/div)



$Performance \ Characteristics \ (continued, V_{IN} = 12V, V_{OUT} = 3.3V, L = 4.7 \mu H, T_A = +25^{\circ}C, unless \ otherwise \ noted.)$





Ordering Information (Note 7)





Package Outline Dimensions (All dimensions in mm(inch).)

Please see http://www.diodes.com/package-outlines.html for the latest version.

Package Type: SO-8EP



Note: Eject hole, oriented hole and mold mark is optional.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Package Type: SO-8EP



Dimensions	Z	G	X	Y	X1	Y1	E
	(mm)/(inch)						
Value	6.900/0.272	3.900/0.154	0.650/0.026	1.500/0.059	3.600/0.142	2.700/0.106	1.270/0.050





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